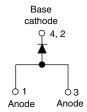


# Schottky Rectifier, 5.5 A



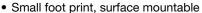


D-PAK	(TO-252AA)
D-FAIL	(10-232AA)

PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I <sub>F(AV)</sub>	5.5 A			
$V_{R}$	40 V			
V <sub>F</sub> at I <sub>F</sub>	See Electrical table			
I <sub>RM</sub>	40 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	9 mJ			

#### **FEATURES**

- Low forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability



- High frequency operation
- Popular D-PAK outline
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

### RoHS COMPLIANT **HALOGEN** FREE

#### **DESCRIPTION**

The VS-50WQ04FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	5.5	Α			
$V_{RRM}$		40	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	340	Α			
V <sub>F</sub>	5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.44	V			
TJ	Range	- 40 to 150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-50WQ04FNHM3	UNITS		
Maximum DC reverse voltage	$V_R$	40	V		
Maximum working peak reverse voltage	$V_{RWM}$	40	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 135 °C, r	5.5			
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	550	Α	
non-repetitive surge current See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	90		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.5 A, L = 8 mH		9	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical		1.2	А	



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST COND	OITIONS	VALUES	UNITS	
		5 A	T <sub>.1</sub> = 25 °C	0.51	V	
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	11=25 0	0.63		
See fig. 1	V <sub>FM</sub> ('')	5 A	T 405.00	0.44		
		10 A	T <sub>J</sub> = 125 °C	0.59		
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	3	A	
See fig. 2	IRM (*)	T <sub>J</sub> = 125 °C		40	mA	
Thereshold voltage	V <sub>F(TO)</sub>	T -T maximum		0.27	V	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		26.77	mΩ	
Typical junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		405	pF	
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm f	rom package body	5.0	nH	

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 40 to 150	°C	
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	3.0	°C/W	
Approximate weight			0.3	g	
Approximate weight			0.01	oz.	
Marking device		Case style D-PAK	50WQ0	4FNH	

#### Note

(1) 
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink

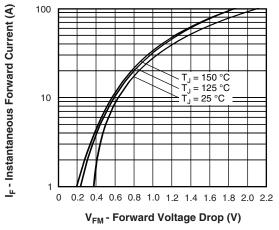


Fig. 1 - Maximum Forward Voltage Drop Characteristics

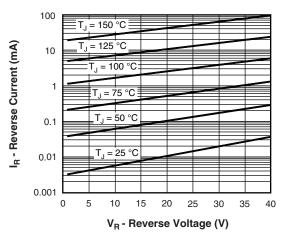


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

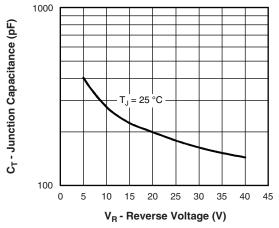


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

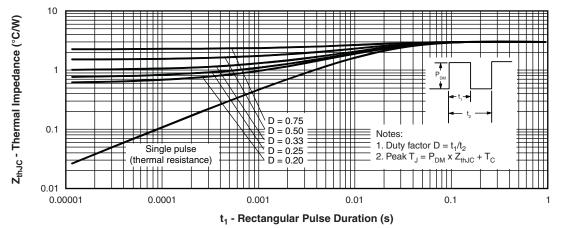


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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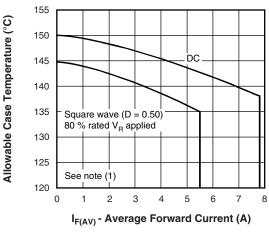


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

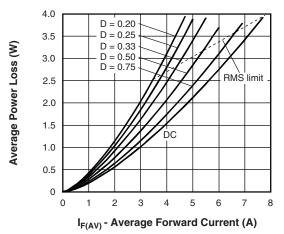


Fig. 6 - Forward Power Loss Characteristics

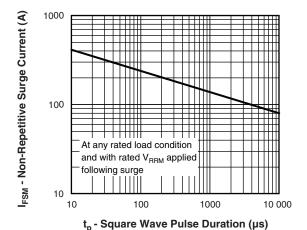


Fig. 7 - Maximum Non-Repetitive Surge Current

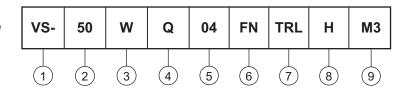
### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>



#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

Current rating (5.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (04 = 40 V)

6 - FN = TO-252AA (D-PAK)

7 - • None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - H = AEC-Q101 qualified

9 - Environmental digit:

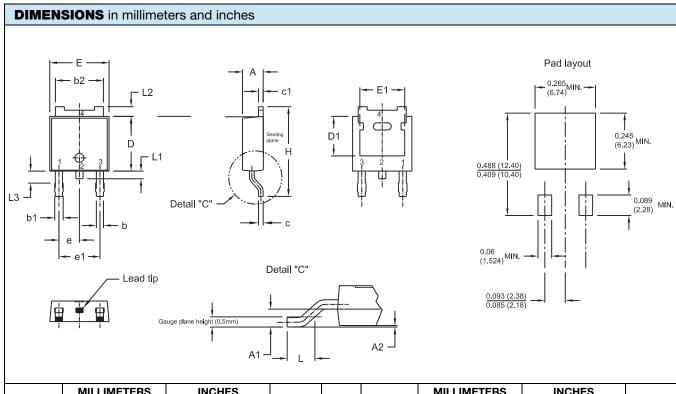
M3 = Halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-50WQ04FNHM3	75	3000	Antistatic plastic tube			
VS-50WQ04FNTRHM3	2000	2000	13" diameter reel			
VS-50WQ04FNTRRHM3	3000	3000	13" diameter reel			
VS-50WQ04FNTRLHM3	3000	3000	13" diameter reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95519			
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033			



# **D-PAK (TO-252AA)**



SYMBOL	MILLIN	IE I EKS	INCHES		NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	2.21	2.38	0.087	0.094		
A2	0.03	0.127	0.001	0.005		
b	0.71	0.88	0.028	0.035		
b1	0.76	1.14	0.030	0.045		
b2	5.23	5.44	0.206	0.214		
С	0.46	0.58	0.018	0.023		
C1	0.46	0.58	0.018	0.023		
D	5.97	6.22	0.235	0.2455		
D1	4.32	4.45	0.170	0.175		
Е	6.48	6.73	0.255	0.2655		
E1	4.49	5.50	0.177	0.217		

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
A1	0.89	1.14	0.035	0.045	
Н	9.65	10.41	0.380	0.410	
L	1.40	1.78	0.055	0.070	
е	2.28	BSC	0.09	BSC	
e1	4.57	BSC	0.18 BSC		
L1	0.64	1.02	0.025	0.040	
L2	0.89	1.27	0.035	0.050	
L3	1.15	1.52	0.040	0.060	
	•				

#### **Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L3 only for reference
- (3) Dimension D1, E1, L2 and b2 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash.
- (5) Outline conforms to JEDEC outline TO-252AA



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